



## DUAL PRECISION CMOS VOLTAGE COMPARATOR WITH OPEN DRAIN OUTPUT DRIVER

### GENERAL DESCRIPTION

The ALD2331A/ALD2331B/ALD2331 is a monolithic high performance dual precision voltage comparator built with advanced silicon gate EPAD<sup>®</sup> CMOS technology intended for high precision analog applications. The ALD2331A/ALD2331B/ALD2331 offers ultra-low input offset voltages and currents at its input pre-amplifier, precision voltage comparator and high-current output driver integrated on-chip, in one industry standard pinout 8 Lead PDIP or SOIC package. Primary features include: very high typical input impedance of  $10^{12}\Omega$ ; low input bias current of 10pA; fast response time of 750ns with only 10mV input step signal; very low power dissipation of 55µA per comparator; and single (+5V) or dual ( $\pm 5V$ ) power supply operation; and 50mA open drain output drivers.

The input voltage range includes ground, making this comparator ideal for low level signal detection with high source impedance. The outputs are open-drain configurations, allowing maximum application flexibility, such as wired-OR connection and various different output loads. An external pull-up resistor is required for each output, although the value of the pull-up resistor can vary over a wide range in order to suit the application needs. The outputs can be connected to a higher external voltage than  $V^+$ .

The ALD2331A/ALD2331B/ALD2331 is ideal for a great variety of precision analog voltage comparator applications, especially low level signal detection circuits requiring low standby power, yet retaining high output current capability as needed.

### FEATURES

- Fanout of 30LS TTL loads
- Guaranteed to drive 200Ω loads
- Low supply current of 55µA typical
- Pinout of LM193 industry standard voltage comparators
- Extremely low input bias currents -- typically 10pA
- Virtually eliminates source impedance effects
- Low operating supply voltage of 3V to 10V
- Single (+5V) and dual supply ( $\pm 5V$ ) operation
- High speed for both large and small level signals -- 300ns typical for TTL inputs
- CMOS, NMOS and TTL compatible
- Wired-OR open drain outputs
- High output sink current -- typically 50mA
- Low supply current spike

### ORDERING INFORMATION ("L" suffix for lead free version)

Operating Temperature Range *	
0°C to +70°C	0°C to +70°C
8-Pin Small Outline Package (SOIC)	8-Pin Plastic Dip Package
ALD2331ASAL	ALD2331APAL
ALD2331BSAL	ALD2331BPAL
ALD2331SAL	ALD2331PAL

\* Contact factory for leaded (non-RoHS) or high temperature versions.

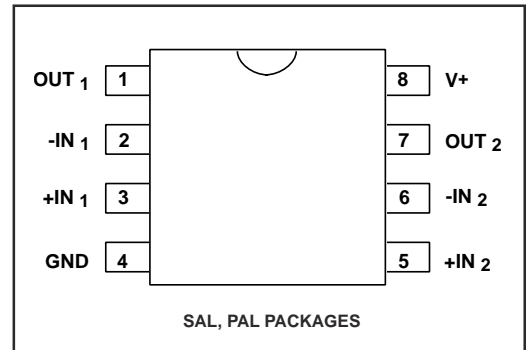
### APPLICATIONS

- Simple precision reference voltage setting
- High source impedance voltage comparison circuits
- MOSFET driver
- Dual limit window comparator
- Power supply voltage monitor
- Photo-detector sensor circuit
- Relay or LED driver
- Oscillators
- Battery operated instruments
- Remote signal detection

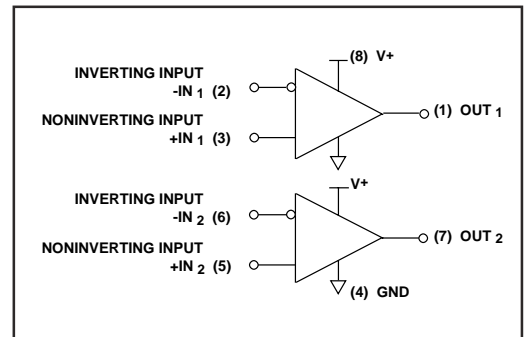
### BENEFITS

- Simple precision reference voltage setting
- On-chip input pre-amplifier and output buffers
- Precision voltage comparison without pre-amplifier
- Eliminates need for second power supply
- Wide range of pull-up resistor values

### PIN CONFIGURATION



### BLOCK DIAGRAM



## ABSOLUTE MAXIMUM RATINGS

Supply voltage, V+	+10.6V
Differential input voltage range	-0.3V to V+ +0.3V
Power dissipation	600 mW
Operating temperature range SAL, PAL packages	0°C to +70°C
Storage temperature range	-65°C to +150°C
Lead temperature, 10 seconds	+260°C

## OPERATING ELECTRICAL CHARACTERISTICS

TA = 25°C V+ = +5V unless otherwise specified

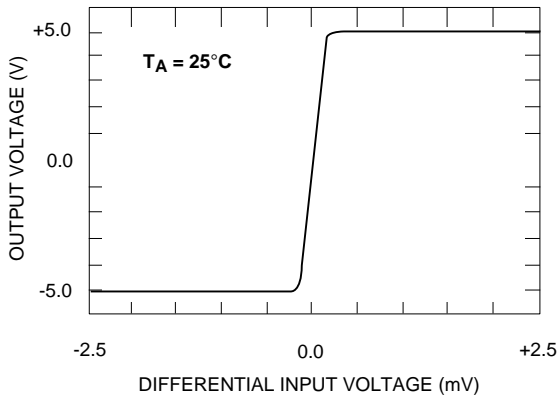
Parameter	Symbol	2331A			2331B			2331			Unit	Test Conditions
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max		
Supply Voltage	V <sub>S</sub> V+	±1.5 3		±5 10	±1.5 3		±5 10	±1.5 3		±5 10	V V	Dual Supply Single Supply
Supply Current	I <sub>S</sub>		110	180		110	180		110	180	μA	No Load Two Comparators
Voltage Gain	AVD	50	150		50	150		50	150		V/mV	R <sub>LOAD</sub> ≥ 15K
Input Offset Voltage	V <sub>OS</sub>		0.2	0.5		0.5	1.0		1.0	2.0	mV	R <sub>LOAD</sub> ≥ 1.5KΩ
Input Offset Current <sup>1</sup>	I <sub>OS</sub>		0.01	20		0.01	20		0.01	20	pA	
Input Bias Current <sup>1</sup>	I <sub>B</sub>		0.01	20		0.01	20		0.01	20	pA	
Common Mode Input Voltage Range <sup>2</sup>	V <sub>ICR</sub>	-0.3		V+ -1.5	-0.3		V+ -1.5	-0.3		V+ -1.5	V	
Low Level Sink Output Voltage	V <sub>OL</sub>		0.15	0.4		0.15	0.4		0.15	0.4	V	I <sub>SINK</sub> = 12mA V <sub>INPUT</sub> = 1V Differential
Low Level Sink Output Current	I <sub>OL</sub>	24	50		24	50		24	50		mA	V <sub>OL</sub> = 1.0 V SINK OUTPUT ON
High Level Sink Output Leakage Current	I <sub>L</sub>		0.01	20		0.01	20		0.01	20	nA	V <sub>OUT</sub> = 5.0 V SINK OUTPUT OFF
Response Time <sup>2</sup>	t <sub>RP</sub>		1.1			1.1			1.1		μs	R <sub>L</sub> = 5.1KΩ, C <sub>L</sub> = 15pF 5mV Input Step/ 5mV Overdrive
	t <sub>RP</sub>		2.4			2.4			2.4		μs	R <sub>L</sub> = 5.1KΩ, C <sub>L</sub> = 15pF 1mV Input Step/ 1mV Overdrive
	t <sub>RP</sub>		600			600			600		ns	R <sub>L</sub> = 5.1KΩ, C <sub>L</sub> = 15pF 100mV Input Step/ 5mV Overdrive
	t <sub>RP</sub>		300			300			300		ns	R <sub>L</sub> = 5.1KΩ, C <sub>L</sub> = 15pF TTL level Input Step
Common Mode Rejection Ratio	CMRR		80			80			80		dB	V <sub>INPUT</sub> = 0V to 2.5V
Power Supply Rejection Ratio	PSRR		75			75			75		dB	V+ = 4V to 5V

Notes: <sup>1</sup> Consists of junction leakage currents

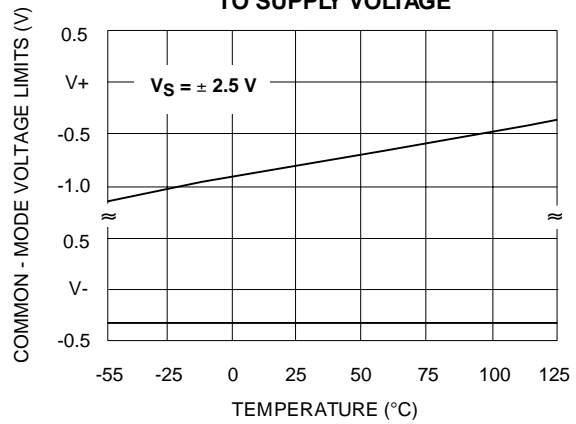
<sup>2</sup> Sample test parameter

# TYPICAL PERFORMANCE CHARACTERISTICS

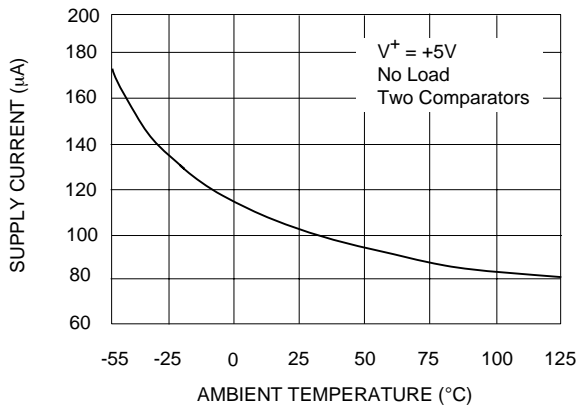
### TRANSFER FUNCTION



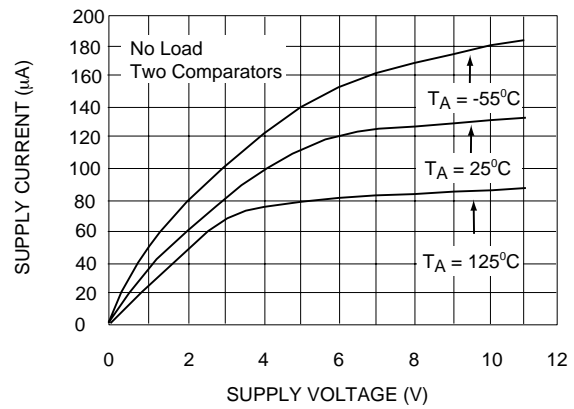
### COMMON - MODE VOLTAGE REFERRED TO SUPPLY VOLTAGE



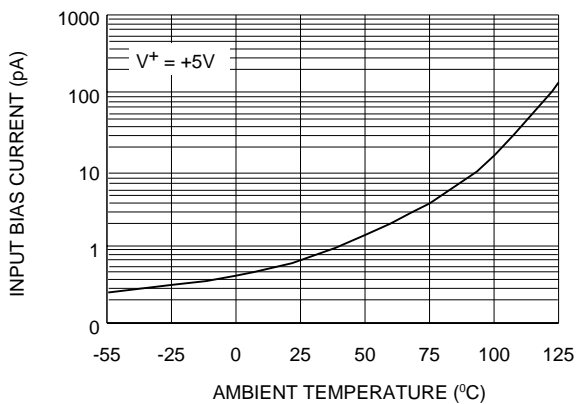
### SUPPLY CURRENT vs. TEMPERATURE



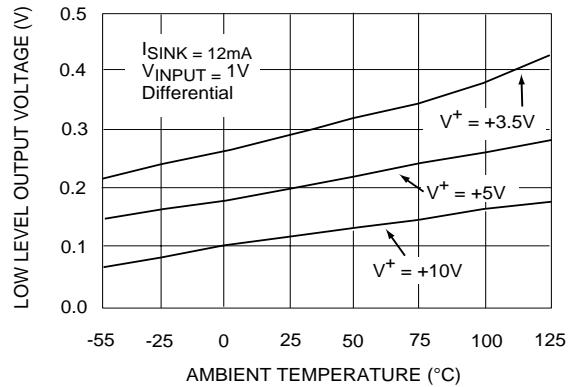
### SUPPLY CURRENT vs. SUPPLY VOLTAGE



### INPUT BIAS CURRENT vs. TEMPERATURE

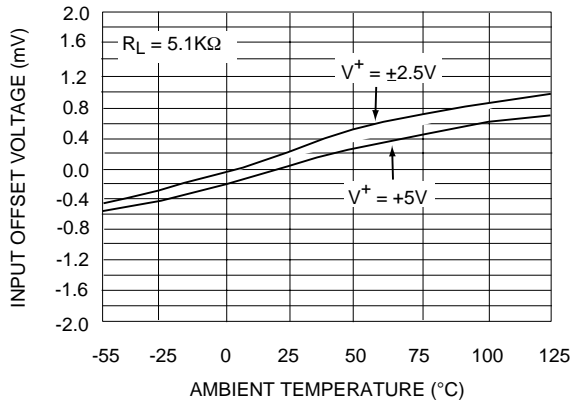


### LOW LEVEL OUTPUT VOLTAGE vs. TEMPERATURE

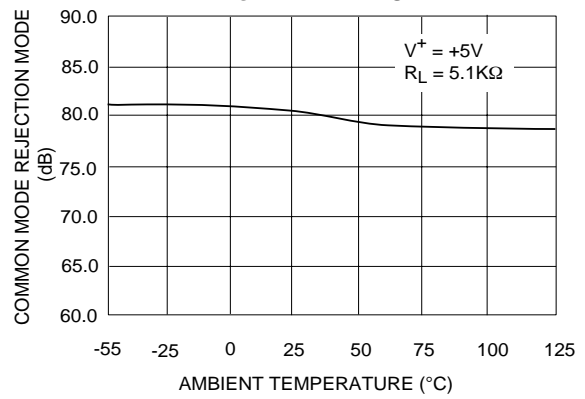


## TYPICAL PERFORMANCE CHARACTERISTICS (cont'd)

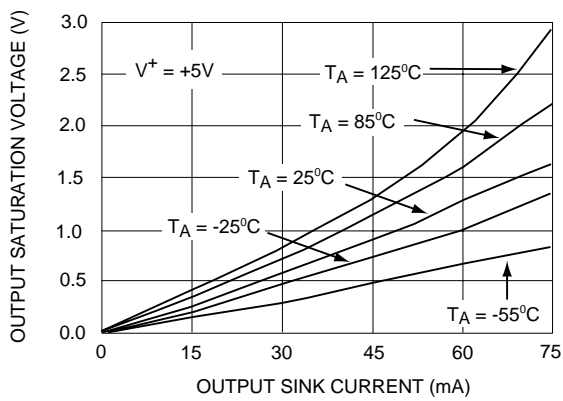
### INPUT OFFSET VOLTAGE vs. TEMPERATURE



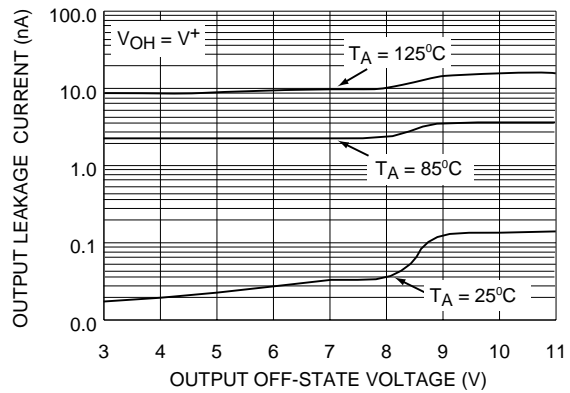
### COMMON MODE REJECTION RATIO vs. TEMPERATURE



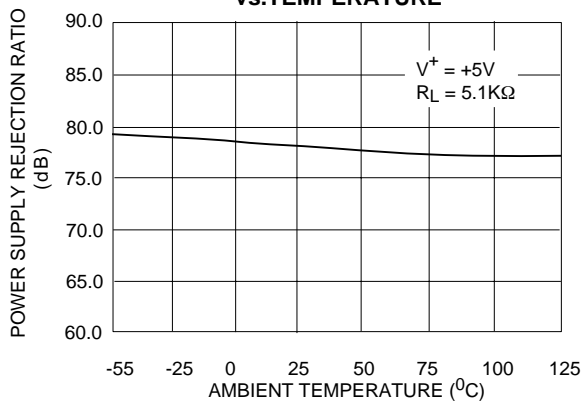
### SATURATION VOLTAGE vs. SINK CURRENT



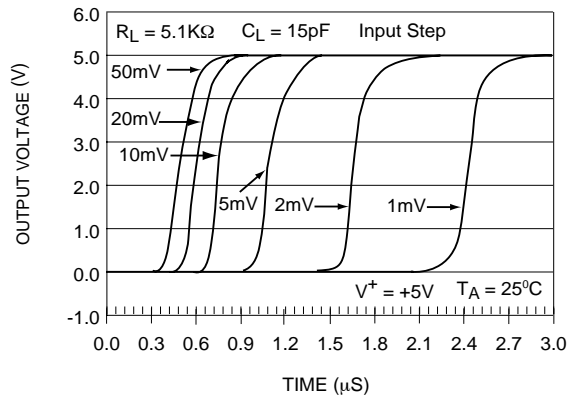
### OUTPUT OFF-STATE VOLTAGE vs. OUTPUT LEAKAGE CURRENT



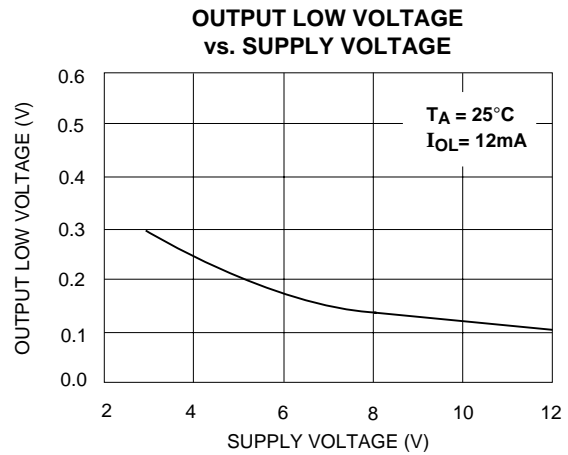
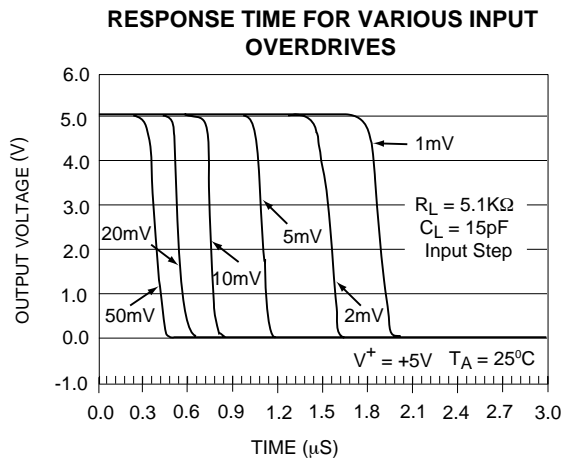
### POWER SUPPLY REJECTION RATIO vs. TEMPERATURE



### RESPONSE TIME FOR VARIOUS INPUT OVERDRIVES

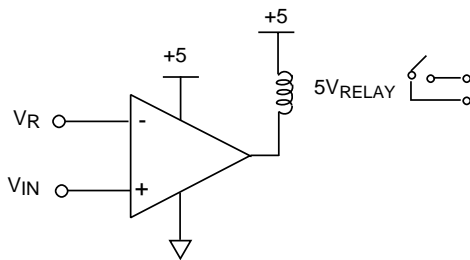


## TYPICAL PERFORMANCE CHARACTERISTICS (cont'd)

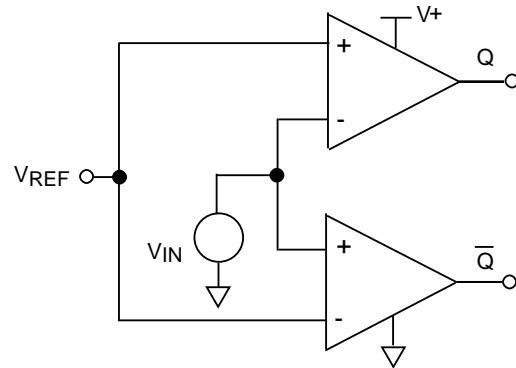


## TYPICAL APPLICATIONS

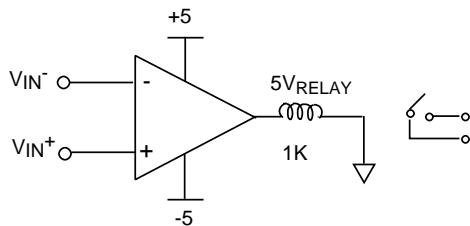
**PRECISION SINGLE SUPPLY VOLTAGE COMPARATOR WITH DIRECT RELAY DRIVER**



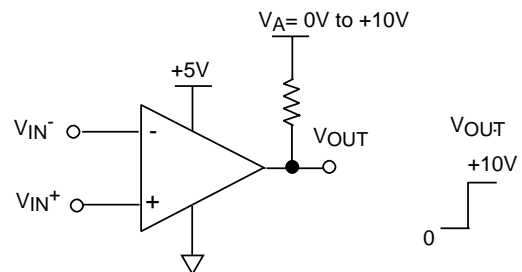
**VOLTAGE COMPARATOR WITH COMPLEMENTARY OUTPUTS**



**VOLTAGE COMPARATOR WITH +/-5V SUPPLY AND +5V RELAY DRIVE**

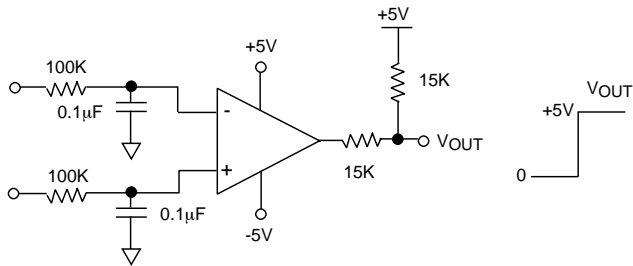


**VOLTAGE COMPARATOR WITH SINGLE SUPPLY AND OUTPUT LEVEL SHIFT**

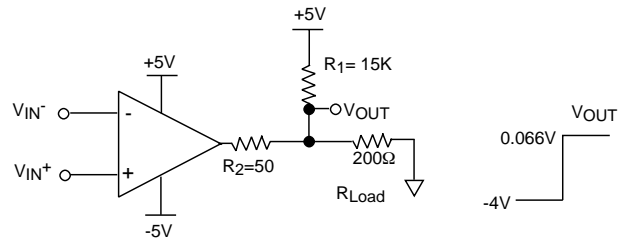


## TYPICAL APPLICATIONS (cont'd)

**VOLTAGE COMPARATOR WITH +/-5V SUPPLY AND OUTPUT LEVEL SHIFT**

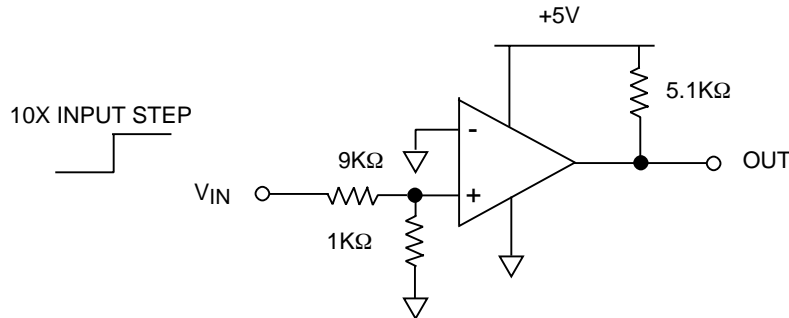


**VOLTAGE COMPARATOR WITH OUTPUT LEVEL SHIFT AND HIGH CURRENT LOAD DRIVER**

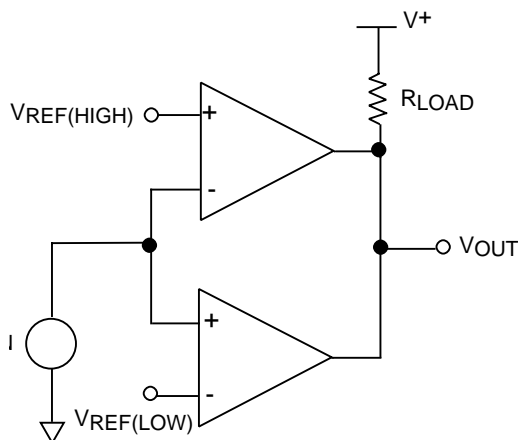


### RESPONSE TIME MEASUREMENT CIRCUIT

Response time is defined as the interval between the application of an input step function and the instant when the output reaches 50% of its maximum value as measured by the following test circuit:



**DUAL LIMIT WINDOW COMPARATOR**

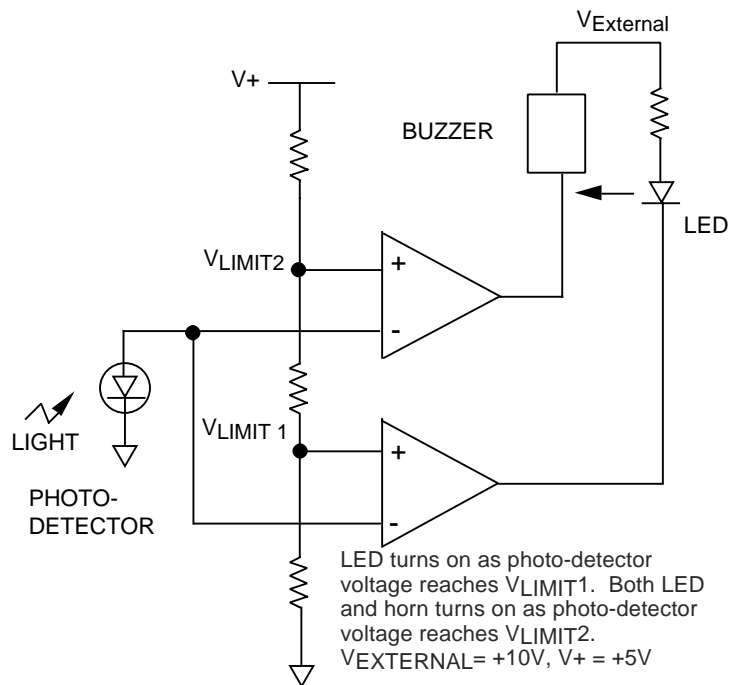


MINIMUM  $R_{LOAD} = 1.5K\Omega$

OUTPUT HIGH FOR  $V_{IN} < V_{REF(HIGH)}$

AND  $V_{IN} > V_{REF(LOW)}$

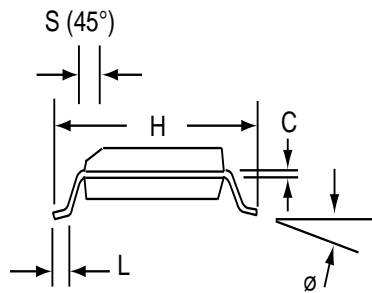
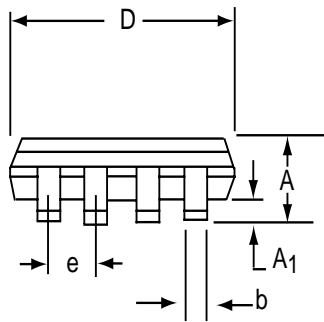
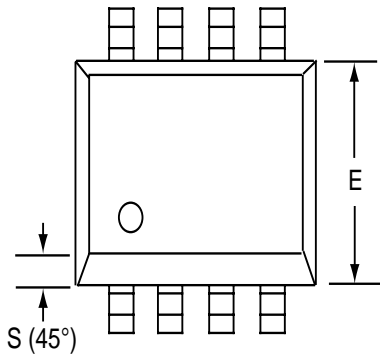
**DUAL LIMIT PHOTO DETECTOR MONITOR**



LED turns on as photo-detector voltage reaches  $V_{LIMIT1}$ . Both LED and horn turns on as photo-detector voltage reaches  $V_{LIMIT2}$ .  
 $V_{EXTERNAL} = +10V$ ,  $V_{+} = +5V$

# SOIC-8 PACKAGE DRAWING

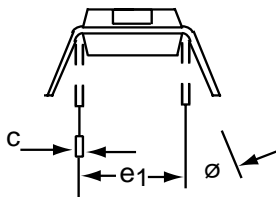
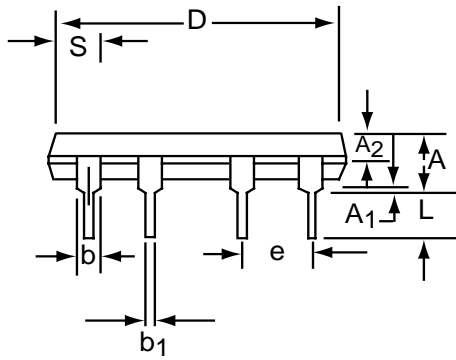
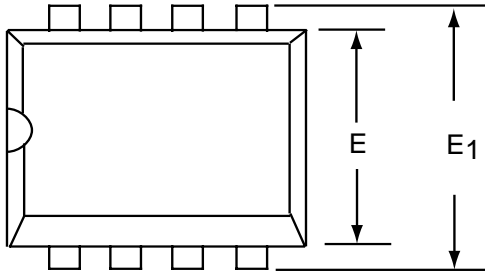
## 8 Pin Plastic SOIC Package



Dim	Millimeters		Inches	
	Min	Max	Min	Max
A	1.35	1.75	0.053	0.069
A <sub>1</sub>	0.10	0.25	0.004	0.010
b	0.35	0.45	0.014	0.018
C	0.18	0.25	0.007	0.010
D-8	4.69	5.00	0.185	0.196
E	3.50	4.05	0.140	0.160
e	1.27 BSC		0.050 BSC	
H	5.70	6.30	0.224	0.248
L	0.60	0.937	0.024	0.037
Ø	0°	8°	0°	8°
S	0.25	0.50	0.010	0.020

# PDIP-8 PACKAGE DRAWING

## 8 Pin Plastic DIP Package



Dim	Millimeters		Inches	
	Min	Max	Min	Max
A	3.81	5.08	0.105	0.200
A <sub>1</sub>	0.38	1.27	0.015	0.050
A <sub>2</sub>	1.27	2.03	0.050	0.080
b	0.89	1.65	0.035	0.065
b <sub>1</sub>	0.38	0.51	0.015	0.020
c	0.20	0.30	0.008	0.012
D-8	9.40	11.68	0.370	0.460
E	5.59	7.11	0.220	0.280
E <sub>1</sub>	7.62	8.26	0.300	0.325
e	2.29	2.79	0.090	0.110
e <sub>1</sub>	7.37	7.87	0.290	0.310
L	2.79	3.81	0.110	0.150
S-8	1.02	2.03	0.040	0.080
∅	0°	15°	0°	15°



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